

MM54HC133/MM74HC133 13-Input NAND Gate

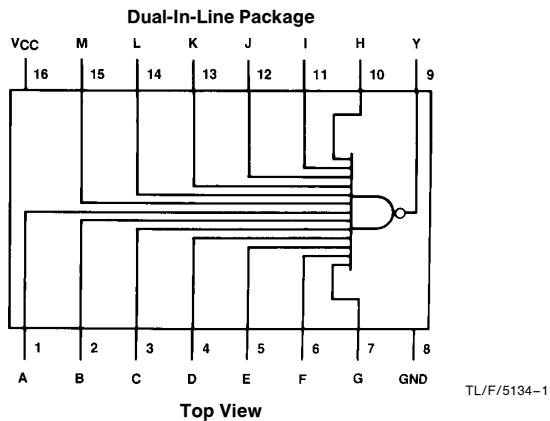
General Description

This NAND gate utilizes advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits. All gates have buffered outputs. All devices have high noise immunity and the ability to drive 10 LS-TTL loads. The 54HC/74HC logic family is functionally as well as pin-out compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

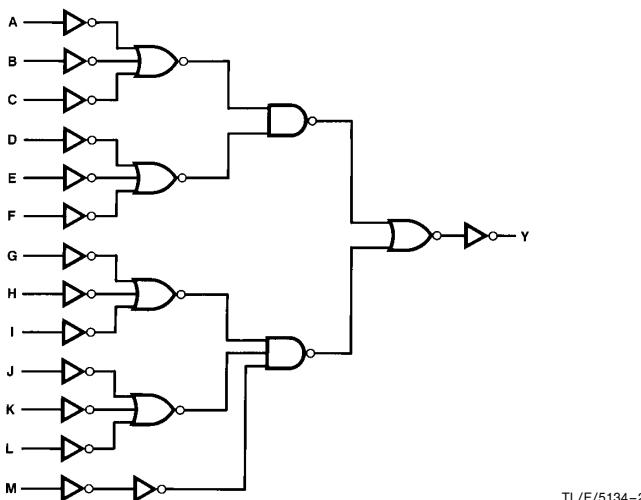
- Typical propagation delay: 20 ns
- Wide power supply range: 2–6V
- Low quiescent current: 20 μ A maximum (74HC Series)
- Low input current: 1 μ A maximum
- Fanout of 10 LS-TTL loads

Connection and Logic Diagrams



Top View

Order Number MM54HC133 or MM74HC133



AC Electrical Characteristics $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 15 pF$, $t_r = t_f = 6 ns$

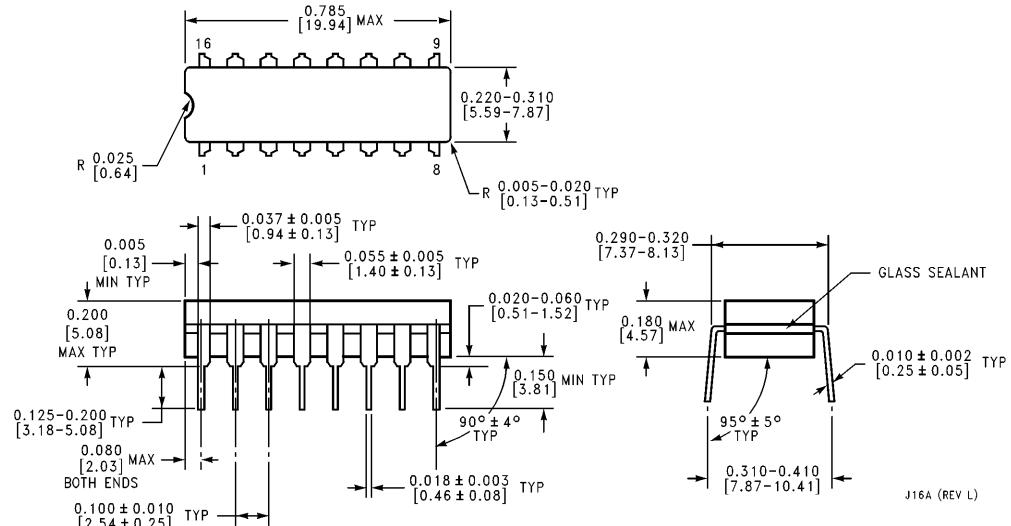
Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay		20	30	ns

AC Electrical Characteristics $V_{CC} = 2.0V$ to $6.0V$, $C_L = 50 pF$, $t_r = t_f = 6 ns$ (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A = 25^{\circ}C$		$74HC$	$54HC$	Units
				Typ		$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	
t_{PHL}, t_{PLH}	Maximum Propagation Delay		2.0V 4.5V 6.0V	66 23 18	160 35 30	190 42 36	220 49 42	ns ns ns
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0V 4.5V 6.0V	25 7 6	75 15 13	95 19 16	110 22 19	ns ns ns
C_{PD}	Power Dissipation Capacitance (Note 5)			34				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

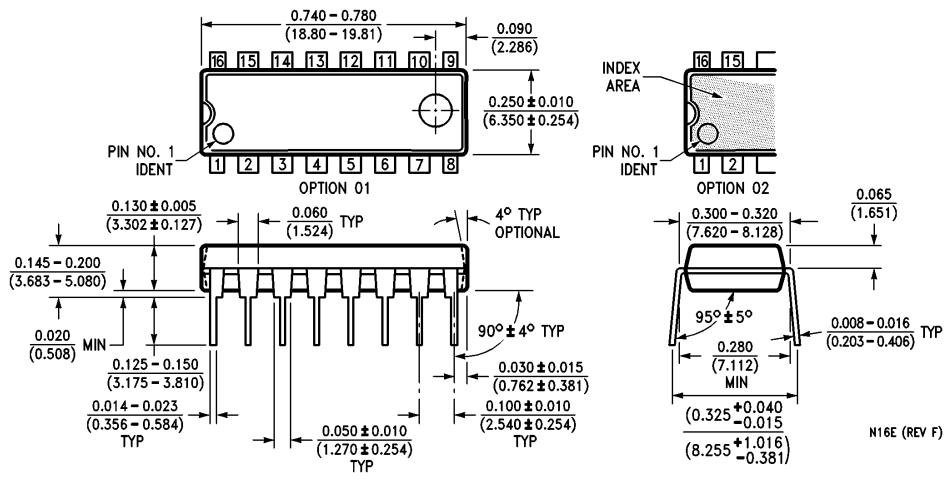
Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

Physical Dimensions inches (millimeters)



Ceramic Dual-In-Line Package (J)
Order Number MM54HC133J or MM74HC133J
NS Package Number J16A

Physical Dimensions inches (millimeters) (Continued)



**Molded Dual-In-Line Package (N)
Order Number MM74HC133N
NS Package Number N16E**

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